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Distinct superconducting properties and hydrostatic pressure effects in 2D α - and β -Mo₂C crystal sheets

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Abstract

Recently, 2D Mo₂C, a new member of the MXene family, has attracted much attention due to the exotic superconducting properties discovered in 2D α -Mo₂C. Here, not only 2D α -Mo₂C but also 2D β -Mo₂C crystal sheets with distinct disordered carbon distributions were successfully grown. 2D β -Mo₂C shows a much stronger superconductivity than 2D α -Mo₂C, and their superconductivities have different hydrostatic pressure responses. The superconducting transition temperature T_c of 2D α -Mo₂C shows a dome-shaped profile under pressure, implying the existence of two competing effects arising from phononic and electronic properties, while for 2D β -Mo₂C, T_c decreases monotonically with increasing pressure, possibly due to phonon stiffening. These results indicate that the electronic properties have a more important influence on the superconductivity in 2D α -Mo₂C compared to 2D β -Mo₂C. The ordered and disordered carbon distributions in 2D α -Mo₂C and β -Mo₂C, respectively, may be the underlying origin for their different electronic and superconducting properties.

Introduction

In the past few years, MXenes, i.e., two-dimensional transition metal carbides (2D TMCs), have received increasing attention due to their tremendous potential for electromagnetic interference shielding, energy storage, catalysis, and electronic devices^{1–5}. As one of the most widely studied 2D TMCs, ultrathin molybdenum carbide (Mo₂C) not only shows a high electronic conductivity but also exhibits exotic superconducting properties at low temperatures⁶. Orthorhombic α -Mo₂C and hexagonal β -Mo₂C are the two stable crystalline forms of the Mo₂C family, but they show distinct ordered and disordered

¹Hefei National Laboratory for Physical Sciences at the Microscale, Department of Physics, and CAS Key Laboratory of Strongly-coupled Quantum Matter Physics, University of Science and Technology of China, Hefei 230026, China ²Shenyang National Laboratory for Materials Science, Institute of Metal Research, Chinese Academy of Sciences, Shenyang 110016, China Full list of author information is available at the end of the article These authors contributed equally: Yunjie Fan, Chuan Xu, Xiang Liu carbon atom distributions, respectively, in almost identical Mo matrices^{7,8}. Early reports showed that the superconducting transition temperatures (T_c) of α -Mo₂C and β -Mo₂C in bulk form lie within wide ranges of 4–12.2 K and 2.4–7.2 K, respectively, due to the inconsistent sample qualities and possible impurity phases⁸.

Recently, Xu et al. successfully synthesized high-quality 2D α -Mo₂C crystal sheets with a chemical vapor deposition (CVD) process⁶. This triggered the discovery of many intriguing properties in this promising 2D TMC system, including 2D superconductivity⁶, quantum phase transitions^{7,9}, nonlinear optical properties¹⁰, and fantastic physics at the interfaces between α -Mo₂C and other 2D materials^{2,11}. The T_c of α -Mo₂C crystal sheets is as high as 3.5 K and becomes lower in thinner crystal sheets, and the superconductivity is suppressed locally at grain boundaries^{6,12,13}. Interestingly, disorder-enhanced superconductivity in α -Mo₂C sheets was observed very recently by scanning tunneling microscopy, which was attributed

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to lattice defect-enhanced disordering and strain-induced strong coupling¹⁴. In addition to the interesting electronic properties, 2D Mo₂C also exhibits unique structural properties. Polarized Raman spectroscopy and transmission electron microscopy studies on 2D α -Mo₂C crystal sheets revealed unique domain structures with 60° and 120° boundaries¹⁵. In particular, it was found that the domain structures can be eliminated and the α -Mo₂C sheets can be transformed into β -Mo₂C by electron beam irradiation⁷. Considering the distinct ordered and disordered carbon atom distributions in α -Mo₂C and β -Mo₂C, respectively, this unique structural feature should have important impacts on the superconductivity owing to the close interaction between the electronic and structural characteristics. However, there are still no reports about the superconductivity in the 2D β -Mo₂C crystal sheet and its differences with 2D α -Mo₂C.

In addition, the superconductivity can be significantly modulated by a basic thermodynamic variable, the hydrostatic pressure (P). A higher dT_c/dP of a superconductor implies that a suitable chemical substitution or epitaxial strain design at ambient pressure may be utilized to achieve an enhanced $T_c^{16,17}$. In particular, research on the superconducting properties under high pressures may help uncover the superconducting mechanism by revealing the impacts of different competing orders in superconducting materials¹⁸. For instance, in simple metal superconductors with *s* or *p* orbital electronic conduction, such as Al, In, Sn, and Pb, a ubiquitous reduction in $T_{\rm c}$ was observed due to stiffening of lattice vibration spectra under pressure, suggesting the importance of phononic properties for the superconductivity¹⁹. For some transition metals with d orbital electronic conduction, such as Tl and Re, the pressure-modulated Fermi surface topology is important for the nonmonotonic pressure dependence of T_{c} , reflecting the critical role and complexity of their electronic properties^{20,21}. For unconventional superconductors, such as high-temperature cuprate superconductors, $T_{\rm c}$ often shows a dome-like pressure dependence due to the complex and strongly correlated electronic effects^{22,23}. However, there is still no research devoted to the pressure effects on the superconductivities of α -Mo₂C and β -Mo₂C thus far. Pressure studies may shed light on the understanding of the superconductivities in Mo₂C of these two structures with different carbon atom distributions.

In this work, the crystal structures and superconductivities of 2D α -Mo₂C and β -Mo₂C sheets were systematically studied. By investigating the electronic transport and superconducting properties under hydrostatic pressures, it was discovered that their T_c , upper critical fields (H_{c2}), pressure responses of the superconductivity, and transport behaviors in normal states are quite different. These different electronic properties may be highly related to the different carbon atom distributions in the α -Mo₂C and β -Mo₂C sheets.

Materials and methods Sample preparation

CVD with a Cu/Mo bilayer substrate was used to grow 2D Mo₂C crystal sheets^{6,13}. Different from our previous report⁶, the formations of rectangular-shaped α -Mo₂C sheets and hexagonal-shaped β -Mo₂C sheets in the same batch were achieved by using a higher flow rate of methane of ~0.6 sccm¹³. The Mo₂C sheet crystals were transferred onto TEM grids for structural characterizations and 10 mm × 10 mm SiO₂ (300 nm)/Si substrates for transport measurements⁶.

Characterizations

The structures were investigated by high angle angular dark field (HAADF)-scanning transmission electron microscopy (STEM) and corresponding selected area electron diffraction (SAED) by TEM with a spherical aberration corrector (Talos F200X). The sample thicknesses were measured by an atomic force microscope (Oxford MFP-3D Infinity). Electron-beam lithography (JEOL JBX-6300FS) and a lift-off process were used to prepare Ti/Au (10/90 nm) electrodes, and e-beam irradiation at 100 kV and 10 nA was performed in the electron-beam lithography equipment. A Quantum Design Physical Property Measurement System (QD PPMS 9T) with an HPC-33 piston-type pressure cell (Daphne 7373 oil as the pressure transmitting medium) was used to perform the resistance measurements at different magnetic fields under various pressures. The superconducting transition temperature of Sn was used to calibrate the magnitude of the pressure.

Results and discussion

Structural characteristics of 2D α -Mo₂C and β -Mo₂C crystal sheets

As reported previously⁶, 2D α -Mo₂C crystals grown by CVD at a low flow rate of methane mainly have 6 kinds of regular shapes (hexagons, rectangles, triangles, etc.), indicating a typical characteristic of good crystallization. In contrast, the 2D Mo₂C sheets used in our study were grown by CVD with a high flow rate of methane and were mostly rectangular and hexagonal, with lateral sizes of 10–20 µm and thicknesses (*d*) of 5–30 nm. The thicknesses of the sheets were measured by atomic force microscopy, and representative images are shown in Supplementary Fig. S1. The superconducting properties of Mo₂C crystal sheets are highly stable under ambient conditions due to their excellent thermal and chemical stabilities.

High-resolution STEM was utilized to characterize the crystal structures of the Mo₂C sheets. Figure 1a, b shows



bright-field TEM images of the Mo₂C crystal sheets of rectangular and hexagonal shapes, respectively, and Fig. 1c, d shows the corresponding SAED patterns. It can be seen that the rectangular- and hexagonal-shaped Mo₂C sheets have different crystal lattice symmetries. The rectangular-shaped sheets of Mo₂C are of the α -phase with an orthorhombic structure. As for the hexagonalshaped sheets, they are of the β -phase with a hexagonal structure. Moreover, the α -Mo₂C sheet grows along the [100] direction, while the β -Mo₂C sheet grows along the [0001] direction, perpendicular to their surfaces. As highlighted by the yellow circles in the SAED pattern shown in Fig. 1c, superlattice diffraction spots are observed for the α -Mo₂C sheets. This feature has been proven to result from the ordered distribution of carbon atoms, which attract each other in the Mo octahedrons, leading to a regular distortion of the hexagonal closepacked Mo lattice^{7,8,24}. In contrast, there is no Mo lattice distortion in the β -Mo₂C sheets because the disordered distribution of carbon atoms mutually offsets the interactions⁷. It is worth mentioning that the α -Mo₂C sheets can be transformed into β -Mo₂C by the electron beam irradiation-induced order-disorder transition⁷. In other words, β -Mo₂C is a disordered counterpart of the ordered α -Mo₂C phase at high temperature²⁵.

Figure 1e, f shows atomic-resolution HAADF-STEM images of α -Mo₂C and β -Mo₂C sheets, respectively. As seen from the magnified images shown in the insets of Fig. 1e, f, there exist extra Mo lattice points (denoted by the green spheres) located at the centers of Mo hexagons, which is due to the stacking faults in the growth direction²⁶. In addition, it can be seen that the Mo atoms in the α -Mo₂C (along the [100] zone axis) and β -Mo₂C (along the [0001] zone axis) sheets have very similar atomic configurations. Actually, α -Mo₂C and β -Mo₂C are closely crystallographically related, namely, $a_{\alpha} = c_{\beta}$, $b_{\alpha} = 2b_{\beta}$, and $c_{\alpha} = \sqrt{3}a_{\beta}$, as illustrated in Fig. 1g. Therefore, considering the almost identical Mo lattices, the main structural difference between α -Mo₂C and β -Mo₂C sheets is the different distributions of carbon atoms.

Another interesting feature is the presence of diagonal domain boundaries in hexagonal β -Mo₂C sheets, as



shown in Fig. 1b. An atomic-resolution HAADF-STEM image near the boundary is shown in Fig. 1f, and the domain boundary is highlighted by the yellow dashed line. Interestingly, the lattice remains unchanged on the two sides of the boundary. The SAED patterns in each domain area are also studied (Supplementary Fig. S2), and the same SAED patterns in all areas indicate that the crystal structure is uniform throughout the whole crystal. It should be noted that diagonal domain boundaries have also been observed in hexagonal-shaped orthorhombic α -Mo₂C crystal sheets, but the lattice of the adjacent domain areas rotates by 60° in plane, which results in different SAED patterns in the neighboring domains^{15,24}. Moreover, the fringe contrast at the domain boundary in Fig. 1f indicates that there exists a translational strain of the Mo lattice at the domain boundary of β -Mo₂C sheets, which is also different from the feature of α -Mo₂C sheets^{15,24}.

Hydrostatic pressure responses of the superconductivities in 2D α -Mo₂C and β -Mo₂C crystal sheets

With the distinct structural features, it will be interesting to study the transport property differences between the α -Mo₂C and β -Mo₂C sheets by tuning a thermodynamic variable—pressure. Figure 2a, b shows the temperature dependences of the sheet resistances (R_s) for a 23.7-nm-thick α -Mo₂C sheet (labeled α -1) and a 13.3-nmthick β -Mo₂C sheet (labeled β -1) at various hydrostatic pressures. R_s is defined by $R_s = \rho/d = RW/L$, where W is the width and *L* is the length. Obviously different pressure effects on T_c were observed for α -Mo₂C and β -Mo₂C sheets, as the pressure dependences of $T_{\rm c}$ in Fig. 2c, d show. Here, the top and bottom lines of the error bars are the onset temperature $T_{c,onset}$ and zero resistance temperature $T_{c,zero}$, respectively, and $T_{c,onset}$, T_c , and $T_{c,zero}$ are defined by the resistance dropping to 90%, 50%, and 0.1% of the normal state resistance, respectively^{27,28}. For α -Mo₂C sheets, $T_{\rm c}$ first increases and then decreases with increasing pressure, presenting a dome-like shape. For β -Mo₂C sheets with T_c higher than that of α -Mo₂C sheets, a monotonic reduction in $T_{\rm c}$ under pressure with ${\rm d}T_{\rm c}/{\rm d}P$ = -0.12 K GPa^{-1} was obtained for β -1. Similar measurements were also performed for a 25.1-nm-thick α -Mo₂C sample (labeled α -2) and a 7.1-nm-thick β -Mo₂C sample (labeled β -2, $dT_c/dP = -0.10 \text{ K GPa}^{-1}$), and consistent pressure effects were observed (Supplementary Fig. S3). In addition, we noted that the resistivity transitions in some of the samples, such as α -1 (Fig. 2a) and β -2 (Fig. S3b), show pronounced shoulders, which may be due to sample inhomogeneity²⁹ (such as domain boundaries²⁴) and/or electrode contact quality.

Here, the hydrostatic pressure effect on the superconductivity of Mo_2C can be discussed in the BCS framework^{30,31}. Typically, the hydrostatic pressure dependences of T_c for BCS superconductors can be analyzed in terms of McMillan theory as follows³²:

$$T_{\rm c} = \frac{\Theta_D}{1.45} \exp\left\{\frac{-1.04(1+\lambda)}{\lambda - \mu^*(1+0.62\lambda)}\right\}.$$
 (1)

Here, Θ_D is the Debye temperature, λ is the electronphonon coupling parameter, and the Coulomb pseudopotential μ^* is equal to 0.1 and is insensitive to pressure^{21,33,34}. Equation (1) has successfully described the pressure-manipulated T_c in many systems, including elemental superconductors¹⁹, transition-metal nitrides³⁵, MgB₂³⁶, LaH₁₀³⁷, *etc*³⁴. Based on Eq. (1), the following relationship can be obtained by the logarithmic volume derivative³³:

$$\frac{d\ln T_{\rm c}}{d\ln V} = -B\frac{d\ln T_{\rm c}}{dP} = -\gamma + \Delta \left\{ \frac{d\ln \eta}{d\ln V} + 2\gamma \right\}, \qquad (2)$$

where V is the sample volume and B is the bulk modulus parameter. $\eta = N(E_{\rm F})\langle I^2 \rangle$ is the product of the Fermilevel density of states $N(E_{\rm F})$ with the average squared electronic matrix element $\langle I^2 \rangle$. $\gamma = - d \ln \langle \omega \rangle / d \ln V$ is the Grüneisen parameter, $\langle \omega \rangle$ is the mean phonon frequency, and $\Delta = 1.04\lambda [1 + 0.38\mu^*] [\lambda - \mu^* (1 + 0.62\lambda)]^{-2.38}$. It can be seen that Eq. (2) contains the electron-phonon coupling, the density of states at the Fermi level, and the energy scale of the phonon excitations (Debye frequency). The terms $\gamma = - d \ln \langle \omega \rangle / d \ln V$ and $d \ln \eta / d \ln V$ represent the variations in the lattice and electronic characteristics with volume, respectively. It has been noted that the electronic term $d \ln \eta / d \ln V$ typically equals -1 for simple metal superconductors (s, p orbital electrons)³⁹ and -3 to -4 for transition metal superconductors (*d* orbital electrons)^{21,33}. For Mo₂C, $N(E_{\rm F})$ is mainly contributed by the 4d orbitals of the molybdenum atoms⁴⁰. According to Eq. (2), the negative electronic term $d \ln \eta / d \ln V$ tends to enhance T_c under pressure²¹. However, for most BCS superconductors, the effect from the pressure-induced phonon stiffening (i.e., $\gamma > 0$) overcomes the effect related to the change in electronic properties, which leads to a ubiquitous decrease in $T_{\rm c}^{21}$.

For β -Mo₂C sheets, the negative $dT_c/dP = -0.12$ K GPa⁻¹ means a positive $-Bd \ln T_c/dP$ on the left side of Eq. (2). Using $T_c = 4.33$ K at ambient pressure, $\Theta_D = 590$ K⁴¹, and $\mu^* = 0.1$, we obtained $\lambda = 0.46$ and $\Delta = 4.46$ from Eq. (1). The electron–phonon coupling parameter $\lambda = 0.46$ is in agreement with the value $\lambda = 0.5$ obtained from first-principles density-functional theory calculations³⁰. Inserting these values, $dT_c/dP = -0.12$ K GPa⁻¹, $d \ln \eta/d \ln V = -3$ to -4, and $B \sim 290$ GPa⁴¹, into Eq. (2), we obtain $\gamma = 2.7$ to 3.3. The large and positive γ suggests significant stiffening of the lattice vibration spectrum under pressure, which results in the reduction in T_c in β -Mo₂C sheets.

For α -Mo₂C sheets, T_c first increases under low pressures and then decreases with further increases in pressure, leading to a distinct dome-like pressure dependence of $T_{\rm c}$, which is obviously different from the decrease in $T_{\rm c}$ in β -Mo₂C sheets. Typically, an increase in T_c with pressure for a BCS superconductor occurs when the effect of the variation arising from the electronic characteristics with pressure overcomes the pressure-induced phonon stiffening effect. For example, in some BCS superconductors (e.g., Lu, Nb₃Ge, and NbSe₂), owing to the pressure-induced complex variation in electronic properties, T_c initially increases under low pressures^{21,42,43}. Similarly, for α -Mo₂C sheets, the increase in T_c under low pressures may also be because the complex variation in electronic properties overcomes the phonon stiffening. For the decrease in $T_{\rm c}$ under high pressures, the phonon stiffening effect may overcome the electronic effect, similar to that in β -Mo₂C sheets. In other words, the distinct pressure responses of the superconductivities in α - and β -Mo₂C suggest their different electronic and phononic properties under pressure. Compared with the always dominant lattice effect in β -Mo₂C sheets, both the lattice and electronic effects play an important role in α -Mo₂C sheets, which may be related to their different carbon atom distributions. The more significant influence of the electronic term in α -Mo₂C should be related to the ordered carbon atoms, while the strong phonon stiffening effect in β -Mo₂C with randomly distributed carbon atoms may be due to the less sensitive pressure response of its electronic characteristic.

Upper critical fields H_{c2} of 2D α -Mo₂C and β -Mo₂C crystal sheets

To further understand the different superconducting characteristics of α -Mo₂C and β -Mo₂C sheets, their upper critical fields $H_{c2}(T)$ (defined by the resistance dropping to 90% of the normal state resistance²⁸) were studied under various pressures. Based on the temperature-dependent resistances measured in various perpendicular magnetic fields under different pressures (Supplementary Fig. S4), the upper critical fields $H_{c2}(T)$ of α -Mo₂C (sample α -1) and β -Mo₂C (sample β -1) sheets are shown in Fig. 3a. For 2D superconducting systems, $H_{c2}(T)$ can be well fitted by the following relationship^{44,45}:

$$H_{c2}(T) = H_{c2}(0) \left(1 - T/T_{c,onset} \right)^{1+\alpha},$$
(3)

where $H_{c2}(0)$ and α are the fitting parameters, and $\alpha \sim 0.34$ and $\alpha \sim 0.04$ are obtained for α -1 and β -1, respectively. Figure 3b shows the pressure dependences of $H_{c2}(0)$ for α -1 and β -1 sheets with distinct nonmonotonic and monotonic curvatures, respectively. At ambient pressure, the $H_{c2}(0)$ for α -Mo₂C sheets is 0.34 T, comparable with earlier reports^{6,13}, while the $H_{c2}(0)$ of 5.55 T for β -Mo₂C







sheets is ~16 times that for α -Mo₂C sheets. The initial slopes $dH_{c2}/dT|_{T=Tc,onset}$ for the α -Mo₂C and β -Mo₂C sheets are -0.06 and -1.11, respectively, and they are almost independent of pressure. Moreover, similar measurements were also performed for the $H_{c2}(T)$ in α -Mo₂C (sample α -3, d = 18.9 nm) and β -Mo₂C (sample β -3, d = 15.6 nm) sheets in parallel magnetic fields, and much larger $H_{c2}(0)$ in parallel magnetic fields than that in perpendicular magnetic fields can be observed, as expected for 2D superconductor systems (Supplementary Fig. S6).

The α -Mo₂C sheet with an ordered carbon atom distribution was considered to be a clean superconductor⁶, while for β -Mo₂C, it should be treated as a dirty superconductor system due to its disordered carbon atom distribution. Typically, for a dirty superconductor, H_{c2} is highly related to the mean free path l and the coherence length ξ as follows⁴⁶:

$$H_{\rm c2}(0) \approx \Phi_0 / 2\pi \xi l \propto 3 \times 10^4 T_{\rm c} / \nu_{\rm F} l, \tag{4}$$

where Φ_0 is the magnetic flux quantum and v_F is the Fermi velocity. The product $v_F l$ is proportional to the electron diffusion coefficient, and a smaller $v_F l$ typically indicates stronger disorder^{47,48}. According to Eq. (4), the H_{c2} of β -Mo₂C should be proportional to its T_c and inversely proportional to $v_F l$. Therefore, the dramatic

enhancement of the H_{c2} in β -Mo₂C can be due to its higher T_c and smaller $v_F l$ induced by the disordered carbon atom distribution. From the above discussions, it can be seen that the significant differences between α -Mo₂C and β -Mo₂C sheets should be related to the electronic structure differences, which are affected by the ordered and disordered carbon distributions. The detailed contributions of the ordered and disordered carbon atom distributions to the electronic structures of Mo₂C require further theoretical studies in the future.

Relationships among the thickness, residual resistivity ratio, and superconductivity of samples

For 2D sheets, the sample thickness generally has a significant influence on the electronic transport properties^{49,50}. It is thus interesting to study the effects of thickness on the superconductivities of α -Mo₂C and β -Mo₂C sheets. Figure 4a, b shows the superconducting transitions of representative α -Mo₂C and β -Mo₂C crystal sheets with different sheet thicknesses, respectively. It can be seen that the values of T_c decrease with decreasing thickness for both α -Mo₂C and β -Mo₂C crystal sheets. Typically, in many superconducting systems, T_c is maximum (T_{c-max}) in the bulk sample and gradually decreases with decreasing sample thickness, and when the thickness is below a certain level (d_c), the sample will no longer be in the superconducting state^{51,52}. Based on the Ginzburg-



Landau equations, Simonin proposed a relationship between T_c and the thickness as follows^{53,54}:

$$T_{\rm c} = T_{\rm c-max} (1 - d_{\rm c}/d).$$
 (5)

Figure 4c shows the evolution of T_c as a function of the inverse of the thickness (1/d), and the experimental results can be fitted very well by Eq. (5) with $T_{c-max} =$ 4.03 K and $d_c = 3.3$ nm (~ 7 unit cells) for α -Mo₂C sheets and $T_{\text{c-max}} = 5.67$ K and $d_{\text{c}} = 2.8$ nm (~ 6 unit cells) for β -Mo₂C sheets. The T_{c-max} values of α - and β -Mo₂C fall in the ranges of their bulk T_c of 4 K-12.2 K and 2.4 K-7.2 K⁸, respectively, and the Mo₂C sheets may no longer be in a superconducting state when the sample thicknesses are below 6~7 unit cells⁵³. Furthermore, the T_c of β -Mo₂C sheets is ~1.6 K higher than that of α -Mo₂C sheets with similar thicknesses. The higher T_c of β -Mo₂C than that of α -Mo₂C may be due to the enhanced electron-phonon coupling related to the disordered carbon distribution in β -Mo₂C¹⁴ as well as the higher Debye temperature of β - Mo_2C (~590 K) than that of α -Mo₂C (~580 K)⁴¹. To further illustrate the role of the carbon distribution in Mo₂C, e-beam irradiation was used to produce varying degrees of disorder in the carbon distribution⁷, and the order-disorder transition from α -Mo₂C to β -Mo₂C results in increases in $T_{\rm c}$ and the sheet resistance (Supplementary Figs. S7 and S8), consistent with Fig. 4.

According to the BCS superconducting mechanism, a stronger electron-phonon coupling, related to the intrinsic phononic and electronic properties, will lead to a higher $T_{\rm c}$, which can be reflected by the normal state properties. For example, in elemental superconductors, a relatively strong electron-phonon coupling often results in a relatively poor electronic conduction^{21,46}, and disorder-enhanced electron-phonon coupling accompanied by an increase in resistivity was also observed in other superconductors, such as Mo₃Ge⁵⁵. Thus, it will be interesting to study the normal state transport behaviors of α -Mo₂C and β -Mo₂C sheets. Figure 5a shows the temperature dependence of the normalized resistance $R_{\rm s}$ / $R_{s-300\text{K}}$ from 1.9 K to 300 K for representative α -Mo₂C (α -4, d = 23.2 nm) and β -Mo₂C (β -4, d = 21.8 nm) sheets with similar thicknesses. A faster decrease in the normalstate resistance with decreasing temperature was observed in the α -Mo₂C sheets, which indicates a stronger metallicity in the α -Mo₂C.

To obtain a more comprehensive assessment of the normal state properties of α -Mo₂C and β -Mo₂C sheets, the thickness dependences of their residual resistance ratio ($RRR = R_{s-300K}/R_{s-6K}$) and sheet resistance at 10 K (R_{s-10K}) are shown in Fig. 5b, c, respectively. Compared with α -Mo₂C sheets, β -Mo₂C shows a much smaller *RRR* and a much higher R_{s-10K} . In particular, the thickness-dependent trends for *RRR* and R_{s-10K} are obviously

different between α -Mo₂C and β -Mo₂C sheets. A thicker α -Mo₂C sheet possesses a higher *RRR* and a smaller R_{s} - $_{10K}$, while a thicker β -Mo₂C sheet has a lower *RRR* and a larger R_{s-10K} . A larger RRR means less electronic scattering, which will lead to a better electrical conductivity, namely, a smaller sheet resistance⁵⁶. The electronic scattering in 2D sheet or film materials mainly results from two aspects: surface and/or interface scattering and intrinsic lattice scattering. In α -Mo₂C sheets, the intrinsic lattice scattering is relatively weak due to the ordered carbon atom distributions, and the surface scattering is dominant. Thus, for α -Mo₂C sheets, the importance of the surface scattering declines for thicker samples, which leads to an overall lower electronic scattering, a higher *RRR*, and a smaller sheet resistance. For β -Mo₂C sheets, the disordered carbon atom distributions will result in strong intrinsic lattice scattering. As a result, the overall stronger lattice scattering in a thicker β -Mo₂C sheet will lead to a smaller RRR and a larger sheet resistance.

Furthermore, the relationships between the T_c and RRR of α -Mo₂C and β -Mo₂C sheets plotted in Fig. 5d show different variation trends, and β -Mo₂C has a higher T_c with a smaller RRR, in contrast to α -Mo₂C. It is worth mentioning that a higher T_c usually accompanies a higher RRR due to the less scattering and higher sample quality^{49,56}, which is the case for α -Mo₂C sheets. In contrast, a higher T_c with a lower RRR was observed in the β -Mo₂C sheets. Considering the almost identical Mo lattices in α -Mo₂C and β -Mo₂C, it can be concluded that although the disordered distribution of carbon atoms increases the electronic scattering, it may promote the electron-phonon coupling and is beneficial for higher T_c , similar to Mo₃Ge⁵⁵.

Conclusions

In summary, the α - and β -phases of Mo₂C sheet crystals with rectangular and hexagonal shapes, respectively, were successfully grown by the CVD technique. It was found that the intriguing superconductivities in Mo₂C sheets of α - and β -phases have different hydrostatic pressure responses. Similar to conventional superconductors, β - Mo_2C sheets have a monotonic decrease in T_c under pressure due to the increase in the average vibration frequency of phonons, while the T_c of α -Mo₂C sheets shows a dome-shaped profile under pressure, which suggests the more critical role of the electronic properties in α -Mo₂C sheets. The β -Mo₂C sheets not only possess a higher T_c but also have a much larger H_{c2} (an order of magnitude larger than that of the α -Mo₂C sheets), which may be related to a stronger electron-phonon coupling strength as well as a smaller $v_{\rm F}l$. Furthermore, the thickness-dependent T_c , RRR, and normal-state resistances were analyzed for α -Mo₂C and β -Mo₂C sheets, and the distinct thickness-dependent trends in the normal state can be explained by the stronger lattice scattering in β -Mo₂C sheets. The distinct superconducting and normal-state electronic properties in α -Mo₂C and β -Mo₂C sheets should be related to their ordered and disordered carbon atom distributions, respectively. Our study provides a deep understanding of the super-conductivity in α -Mo₂C sheets and lays the groundwork for future research into β -Mo₂C sheets, and the results may have great implications in the study of MXenes and superconductivity.

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C.X. prepared the samples in the lab led by W.C.R. and H.M.C. X.L., Y.J.F., and C. M. performed the measurements. X.G.L., Y.W.Y., and W.C.R. designed and supervised the experiments. Y.J.F., X.L., W.C.R., Y.W.Y., and X.G.L. wrote the manuscript. All the authors contributed to the refinement of the manuscript. Y. J.F., C.X., and X.L. contributed equally.

Conflict of interest

The authors declare that they have no conflict of interest.

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